



#### P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

V <sub>(BR)DSS</sub>	RDS(ON) max	I <sub>D</sub> T <sub>A</sub> = +25°C
	$77m\Omega@V_{GS} = -10V$	-3.5A
-30V	$95m\Omega@V_{GS} = -4.5V$	-3.0A
	150mΩ@ $V_{GS} = -2.5V$	-2.4A

### **Description and Applications**

This MOSFET has been designed to meet the stringent requirements of Automotive applications. It is qualified to AECQ101, supported by a PPAP and is ideal for use in:

- DC-DC Converters
- Power Management Functions
- Analog Switch

### **Features and Benefits**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- · Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

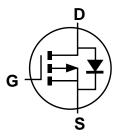
#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (£3)
- Terminal Connections: See Diagram
- Weight: 0.009 grams (Approximate)

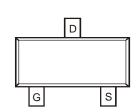








**Equivalent Circuit** 



Top View

#### **Ordering Information (Note 5)**

Part Number	Case	Packaging	
DMP3130LQ-7	SOT23	3000/Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html

## Marking Information



P5S = Product Type Marking Code YM or  $\overline{Y}M$  = Date Code Marking Y or  $\overline{Y}$  = Year (ex: D = 2016) M = Month (ex: 9 = September)

Date Code Kev

Year	2016		2017	2018		2019	2020		2021	2022		2023
Code	D		Е	F		G	Н		l	J		K
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage		$V_{DSS}$	-30	V	
Gate-Source Voltage		$V_{GSS}$	±12	V	
Continuous Drain Current (Note 6) 1/ 451/	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	l <sub>D</sub>	-3.5 -2.6	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = -4.5V	$t < 10s$ $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		I <sub>D</sub>	-4.1 -3.2	А
Maximum Continuous Body Diode Forward Current	(Note 6)	Is	-1.6	А	
Pulsed Drain Current (10µs pulse, duty cycle = 1%)		I <sub>DM</sub>	-20	А	

### **Thermal Characteristics**

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	р	0.7	W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	$P_{D}$	0.4	VV
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	184	°C/W
Thermal Resistance, Junction to Ambient (Note 0)	t<10s	$R_{\theta JA}$	115	C/VV
Total Power Dissipation (Note 7)	$T_A = +25^{\circ}C$	D-	1.3	W
Total Power Dissipation (Note 7)	$T_A = +70^{\circ}C$	$P_D$	0.8	VV
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	р	94	
Thermal Resistance, Junction to Ambient (Note 7)	t<10s	$R_{\theta JA}$	61	°C/W
Thermal Resistance, Junction to Case		$R_{ hetaJC}$	25	
Operating and Storage Temperature Range		$T_{J_1}T_{STG}$	-55 to +150	°C

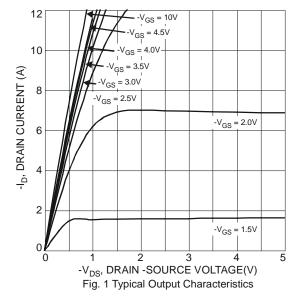
# **Electrical Characteristics** (@ $T_A = \pm 25$ °C, unless otherwise specified.)

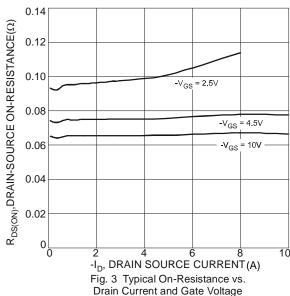
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 8)								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-1	μA	$V_{DS} = -30V, V_{GS} = 0V$		
Gate-Body Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 8)								
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.6	_	-1.3	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		
		_	59	77		$V_{GS} = -10V, I_D = -4.2A$		
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	73	95	mΩ	$V_{GS} = -4.5V, I_D = -4A$		
		_	115	150		$V_{GS} = -2.5V, I_D = -3A$		
Forward Transconductance	g <sub>fs</sub>	_	8	_	S	$V_{DS} = -5V, I_{D} = -4A$		
Source-Drain Diode Forward Voltage	$V_{SD}$	_	-0.8	-1.25	V	$V_{GS} = 0V, I_S = -3.0A$		
DYNAMIC CHARACTERISTICS (Note 9)								
Input Capacitance	Ciss	_	432	864	pF	45)/ )/ 6)/		
Output Capacitance	Coss		87	174	рF	V <sub>DS</sub> = -15V, V <sub>GS</sub> = 0V f = 1.0MHz		
Reverse Transfer Capacitance	Crss	_	62	124	pF	1 = 1.0ivii iz		
Gate Resistance	R <sub>G</sub>	_	4.04	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$		
SWITCHING CHARACTERISTICS (Note 9)								
Total Gate Charge	$Q_G$		5.9	11.8	nC	$V_{DS} = -15V$ , $V_{GS} = -4.5V$ , $I_{D} = -4.0A$		
Total Gate Charge	<b>Q</b> G		12	24		$V_{DS} = -15V$ , $V_{GS} = -10V$ , $I_{D} = -4.0A$		
Gate-Source Charge	$Q_{GS}$	_	1.0	2.0		V 45V V 45V L 40A		
Gate-Drain Charge	$Q_{GD}$	_	3.1	6.2		$V_{DS} = -15V$ , $V_{GS} = -4.5V$ , $I_{D} = -4.0A$		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	4.6	9.2				
Rise Time	t <sub>R</sub>	_	6.5	13.0	ns	$V_{DS} = -15V, V_{GS} = -10V,$		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	27.8	55.6		$I_D = -1A, R_G = 6.0\Omega$		
Fall Time	t <sub>F</sub>	_	15.0	30.0				

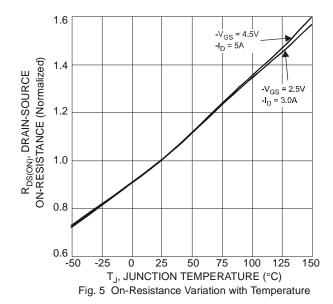
Notes:

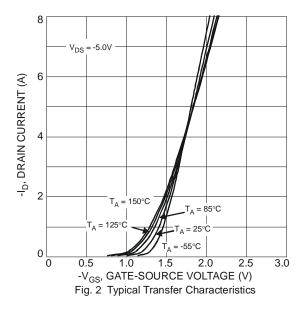
- 6. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
  7. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.
  8. Short duration pulse test used to minimize self-heating effect.
  9. Guaranteed by design. Not subject to production testing

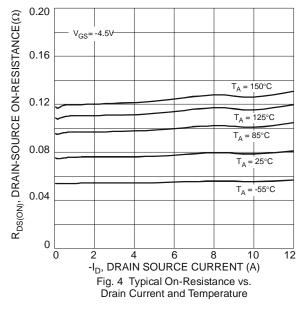












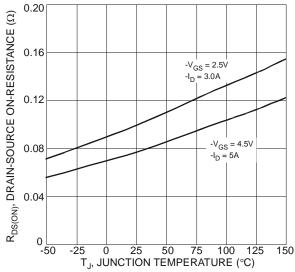


Fig. 6 On-Resistance Variation with Temperature



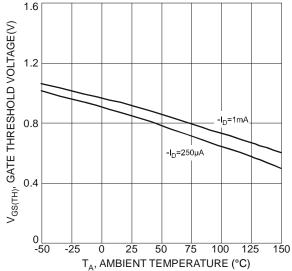
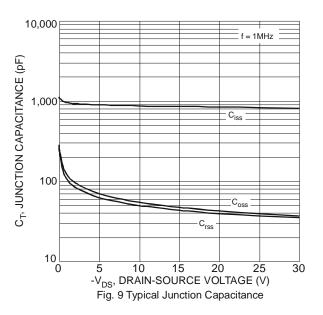
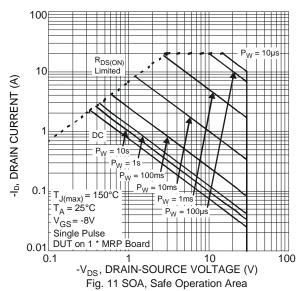
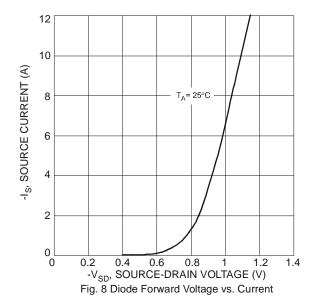
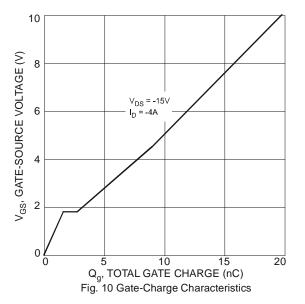


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

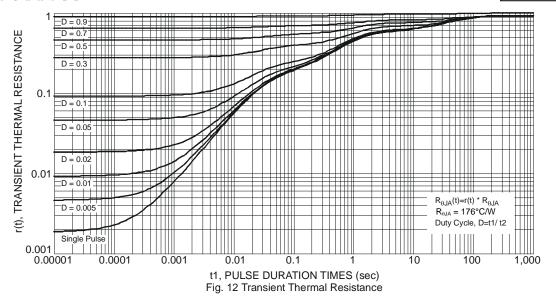








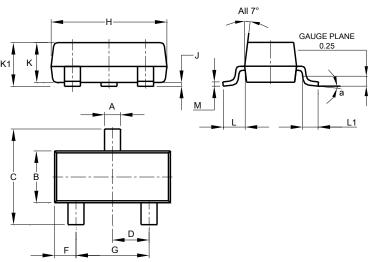




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

## SOT23

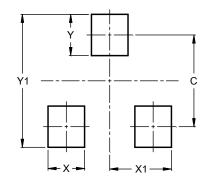


SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All Dimensions in mm								

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Υ	0.9
Y1	2.9

March 2016



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